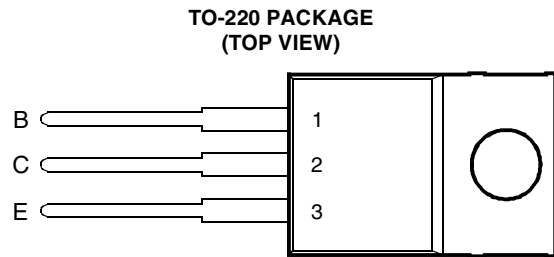




- Designed for Complementary Use with BDT60, BDT60A, BDT60B and BDT60C
- 50 W at 25°C Case Temperature
- 4 A Continuous Collector Current
- Minimum  $h_{FE}$  of 750 at 1.5V, 3 A



Pin 2 is in electrical contact with the mounting base.

MDTRACA

**absolute maximum ratings at 25°C case temperature (unless otherwise noted)**

RATING		SYMBOL	VALUE	UNIT
Collector-base voltage ( $I_E = 0$ )	BDT61	$V_{CBO}$	60	V
	BDT61A		80	
	BDT61B		100	
	BDT61C		120	
Collector-emitter voltage ( $I_B = 0$ )	BDT61	$V_{CEO}$	60	V
	BDT61A		80	
	BDT61B		100	
	BDT61C		120	
Emitter-base voltage		$V_{EBO}$	5	V
Continuous collector current		$I_C$	4	A
Continuous base current		$I_B$	0.1	A
Continuous device dissipation at (or below) 25°C case temperature (see Note 1)		$P_{tot}$	50	W
Continuous device dissipation at (or below) 25°C free air temperature (see Note 2)		$P_{tot}$	2	W
Operating junction temperature range		$T_j$	-65 to +150	°C
Storage temperature range		$T_{stg}$	-65 to +150	°C
Operating free-air temperature range		$T_A$	-65 to +150	°C

NOTES: 1. Derate linearly to 150°C case temperature at the rate of 0.4 W/°C.  
2. Derate linearly to 150°C free air temperature at the rate of 16 mW/°C.

**PRODUCT INFORMATION**

AUGUST 1993 - REVISED SEPTEMBER 2002  
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**electrical characteristics at 25°C case temperature (unless otherwise noted)**

PARAMETER	TEST CONDITIONS			MIN	TYP	MAX	UNIT
$V_{(BR)CEO}$ Collector-emitter breakdown voltage	$I_C = 30 \text{ mA}$	$I_B = 0$	(see Note 3)	BDT61 BDT61A BDT61B BDT61C	60 80 100 120		V
$I_{CEO}$ Collector-emitter cut-off current	$V_{CE} = 30 \text{ V}$ $V_{CE} = 40 \text{ V}$ $V_{CE} = 50 \text{ V}$ $V_{CE} = 60 \text{ V}$	$I_B = 0$		BDT61 BDT61A BDT61B BDT61C		0.5 0.5 0.5 0.5	mA
$I_{CBO}$ Collector cut-off current	$V_{CB} = 60 \text{ V}$ $V_{CB} = 80 \text{ V}$ $V_{CB} = 100 \text{ V}$ $V_{CB} = 120 \text{ V}$ $V_{CB} = 30 \text{ V}$ $V_{CB} = 40 \text{ V}$ $V_{CB} = 50 \text{ V}$ $V_{CB} = 60 \text{ V}$	$I_E = 0$	$T_C = 150^\circ\text{C}$ $T_C = 150^\circ\text{C}$ $T_C = 150^\circ\text{C}$ $T_C = 150^\circ\text{C}$	BDT61 BDT61A BDT61B BDT61C BDT61 BDT61A BDT61B BDT61C		0.2 0.2 0.2 0.2 2.0 2.0 2.0 2.0	mA
$I_{EBO}$ Emitter cut-off current	$V_{EB} = 5 \text{ V}$	$I_C = 0$				5	mA
$h_{FE}$ Forward current transfer ratio	$V_{CE} = 3 \text{ V}$	$I_C = 1.5 \text{ A}$	(see Notes 3 and 4)		750		
$V_{CE(sat)}$ Collector-emitter saturation voltage	$I_B = 6 \text{ mA}$	$I_C = 1.5 \text{ A}$	(see Notes 3 and 4)			2.5	V
$V_{BE(on)}$ Base-emitter voltage	$V_{CE} = 3 \text{ V}$	$I_C = 1.5 \text{ A}$	(see Notes 3 and 4)			2.5	V
$V_{EC}$ Parallel diode forward voltage	$I_E = 1.5 \text{ A}$	$I_B = 0$				2	V

NOTES: 3. These parameters must be measured using pulse techniques,  $t_p = 300 \mu\text{s}$ , duty cycle  $\leq 2\%$ .

4. These parameters must be measured using voltage-sensing contacts, separate from the current carrying contacts.

**thermal characteristics**

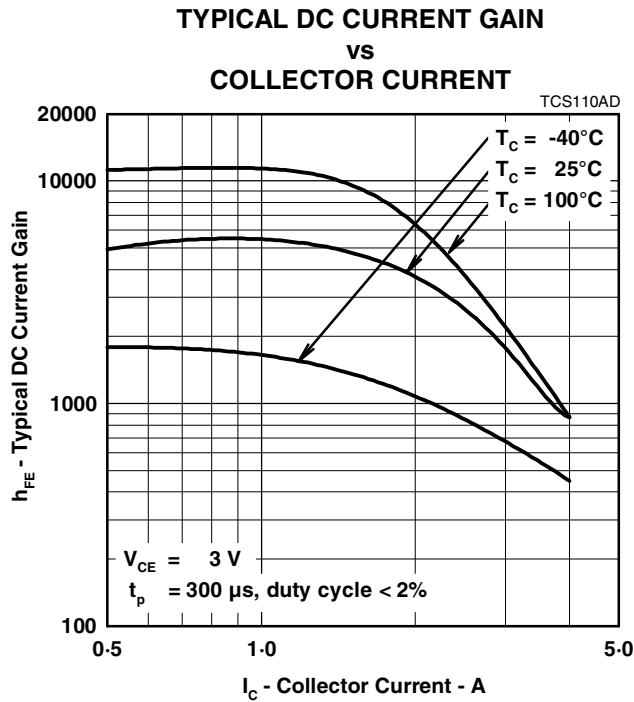
PARAMETER	MIN	TYP	MAX	UNIT
$R_{\theta JC}$ Junction to case thermal resistance			2.5	$^\circ\text{C/W}$
$R_{\theta JA}$ Junction to free air thermal resistance			62.5	$^\circ\text{C/W}$

**resistive-load-switching characteristics at 25°C case temperature**

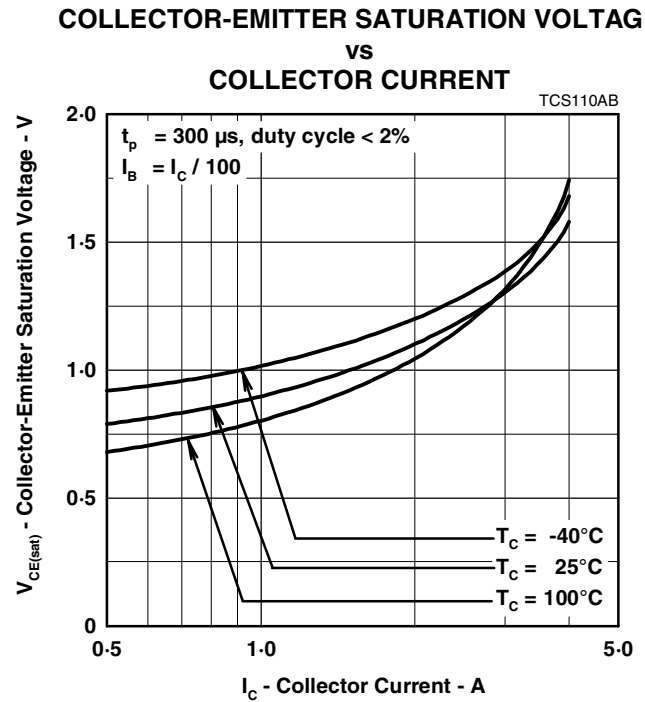
PARAMETER	TEST CONDITIONS <sup>†</sup>			MIN	TYP	MAX	UNIT
$t_{on}$ Turn-on time	$I_C = 2 \text{ A}$	$I_{B(on)} = 8 \text{ mA}$	$I_{B(off)} = -8 \text{ mA}$		1		$\mu\text{s}$
$t_{off}$ Turn-off time	$V_{BE(off)} = -5 \text{ V}$	$R_L = 20 \Omega$	$t_p = 20 \mu\text{s}$ , $dc \leq 2\%$		4.5		$\mu\text{s}$

<sup>†</sup> Voltage and current values shown are nominal; exact values vary slightly with transistor parameters.

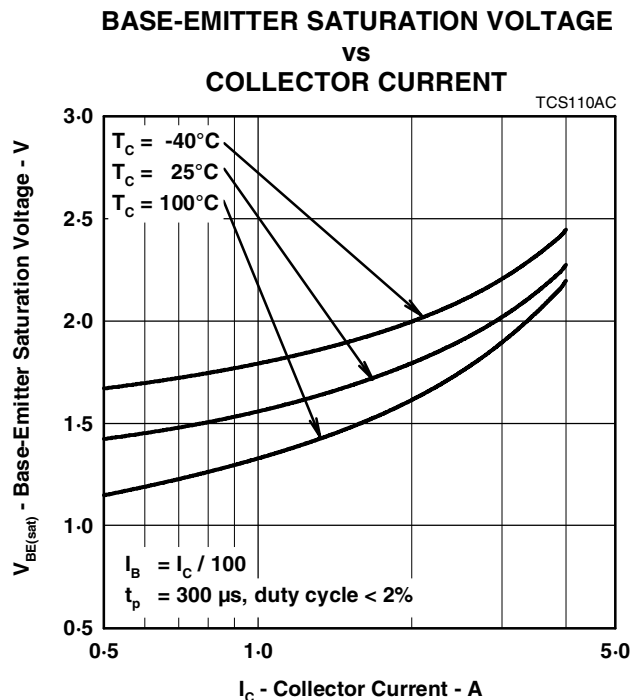
**TYPICAL CHARACTERISTICS**



**Figure 1.**



**Figure 2.**



**Figure 3.**

**PRODUCT INFORMATION**

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## MAXIMUM SAFE OPERATING REGIONS

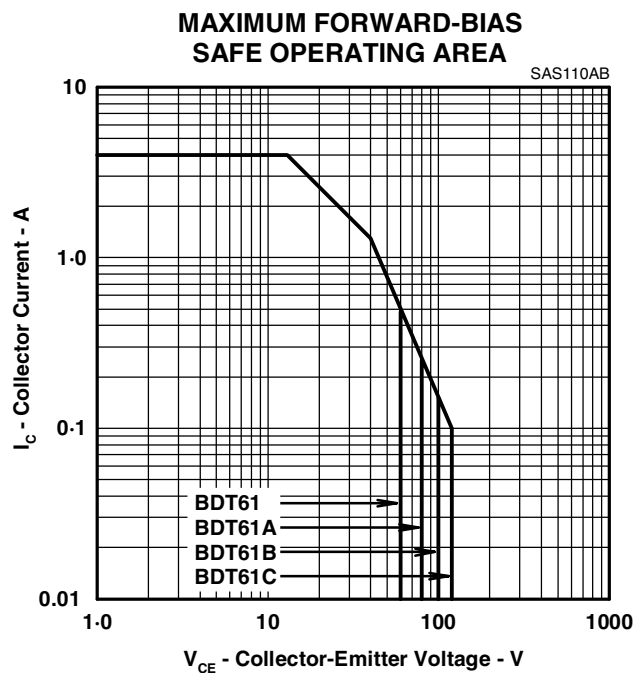


Figure 4.

## THERMAL INFORMATION

### MAXIMUM POWER DISSIPATION vs CASE TEMPERATURE

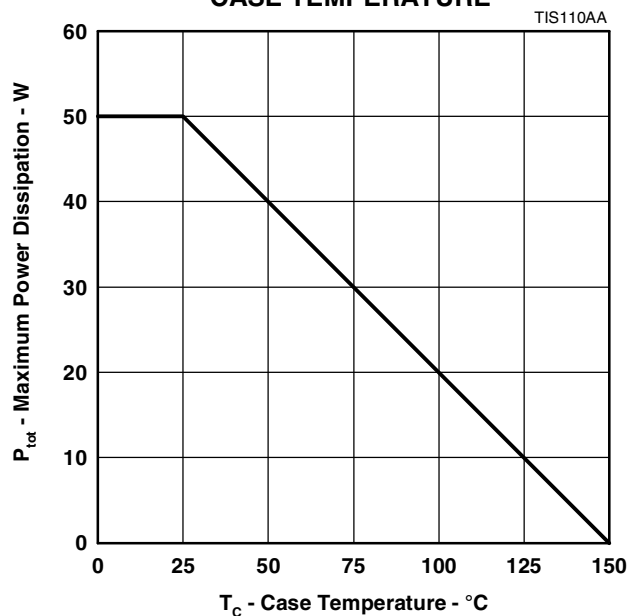


Figure 5.

## PRODUCT INFORMATION

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# TO-220

This single-in-line package consists of a circuit mounted on a lead frame and encapsulated within a plastic compound. The compound will withstand soldering temperature with no deformation, and circuit performance characteristics will remain stable when operated in high humidity conditions. Leads require no additional cleaning or processing when used in soldered assembly.

